

R-C Thermal Model Parameters

DESCRIPTION

The parametric values in the R-C thermal model have been derived using curve-fitting techniques. R-C values for the electrical circuit in the Foster/Tank and Cauer/Filter configurations are included. When implemented in P-Spice, these values have matching characteristic curves to the single-pulse transient thermal impedance curves for the MOSFET.

These RC values can be used in the P-SPICE simulation to evaluate the thermal behavior of the MOSFET junction temperature under a defined power profile. These techniques are described in Application Note AN609, "Thermal Simulation of Power MOSFETs on the P-Spice Platform."

R-C THERMAL MODEL FOR TANK CONFIGURATION



R-C VALUES FOR TANK CONFIGURATION			
Thermal Resistance ($^{\circ}\text{C}/\text{W}$)			
Junction to	Ambient	Case	Foot
RT1	6.1559	746.6000 m	N/A
RT2	14.7162	3.0344	N/A
RT3	17.2013	1.4784	N/A
RT4	42.9266	2.7406	N/A
Thermal Capacitance (Joules/ $^{\circ}\text{C}$)			
Junction to	Ambient	Case	Foot
CT1	602.5703 u	1.4620 m	N/A
CT2	348.6285 m	14.0658 m	N/A
CT3	16.9889 m	140.8596 u	N/A
CT4	2.1900	2.5035 m	N/A

This document is intended as a SPICE modeling guideline and does not constitute a commercial product data sheet. Designers should refer to the appropriate data sheet of the same number for guaranteed specification limits.

R-C THERMAL MODEL FOR FILTER CONFIGURATION**R-C VALUES FOR FILTER CONFIGURATION**

Thermal Resistance (°C/W)			
Junction to	Ambient	Case	Foot
RF1	6.6824	2.2496	N/A
RF2	19.7485	2.9785	N/A
RF3	18.5959	1.9512	N/A
RF4	35.9732	820.7000 m	N/A
Thermal Capacitance (Joules/°C)			
Junction to	Ambient	Case	Foot
CF1	603.4429 u	119.9523 u	N/A
CF2	16.6061 m	1.9816 m	N/A
CF3	389.9565 m	4.5122 m	N/A
CF4	2.2443	72.6905 m	N/A

Note

NA indicates not applicable

